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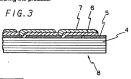
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Method for forming a thin film pattern.

A method for forming a thin film pattern comprising the steps in sequence of forming a lift-off layer is reverse to a desired thin film pattern of the lift-off layer is reverse to a desired thin film pattern, forming a thin film (3) on the substrate, proving a undesirable portion of the thin film (3) by the substrate, producing a semiconductor device (8) comprising the steps in sequence of forming a first electrode (5) and insulated substrate (4), removing a part of the first electrode (5), forming a semiconductor including amorphous material (6) on the first electrode (5), forming a lift-off layer on the semiconductor including amorphous material at such a place whereon a second electrode is not desired to be formed.

and forming a second electrode (7) on the semiconductor.

According to the present invention, a thin film pattern can be formed at low production cost, with high productivity and accuracy, and with less danger during the process.



EUROPEAN SEARCH REPORT

EP 86 10 2335

DOCUMENTS CONSIDERED TO BE RELEVANT					
Category	Citation of document w of rele	ith indication, where appropriate, want passages	Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int. Cl. 4)	
х	DE-A-2 420 394 * Page 5, las 14, paragraph 1	(CANON K.K.) t paragraph - page; claims; figures	1,2,4 6,13, 14,17	H 01 L H 01 L H 01 L	
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х	US-A-4 218 532 LABORATORIES)	(BELL TELEPHONE	1,6,10 ,13,1		
l	* Claims; figur	es 1-8 *			
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	* Claims; figures *				
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	paragraph 1; claims; figures *				
	The present search report has t	oeen drawn up for all claims			
Place of search Date of completion of the search				Examiner	
	THE HAGUE CATEGORY OF CITED DOCE	16-10-1987		JN M. ying the invention	

- particularly relevant if taken alone
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 A: technological background
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- & : member of the same patent family, corresponding document